



RN2606(TE85L,F) Information



For Reference Only

Part Number RN2606(TE85L,F)

ManufacturerToshiba Semiconductor and StorageCategoryDiscrete Semiconductor Products

Transistors - Bipolar (BJT) - Arrays, Pre-Biased

Description TRANS 2PNP PREBIAS 0.3W SM6

Package SC-74, SOT-457

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









RN2606(TE85L,F) Specifications

Manufacturer Part Number	RN2606(TE85L,F)
Manufacturer	Toshiba Semiconductor and Storage
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Arrays, Pre-Biased
Package	SC-74, SOT-457
Series	-
Transistor Type	2 PNP - Pre-Biased (Dual)
Current - Collector (Ic) (Max)	100mA
Voltage - Collector Emitter Breakdown (Max)	50V
Resistor - Base (R1) (Ohms)	4.7k
Resistor - Emitter Base (R2) (Ohms)	47k
DC Current Gain (hFE) (Min) @ Ic, Vce	80 @ 10mA, 5V
Vce Saturation (Max) @ Ib, Ic	300mV @ 250μA, 5mA
Current - Collector Cutoff (Max)	100nA (ICBO)
Frequency - Transition	200MHz
Power - Max	300mW
Mounting Type	Surface Mount
Package / Case	SC-74, SOT-457
Supplier Device Package	SM6
	Report errors?

RN2606(TE85L,F) Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

RN2606(TE85L,F) Payment Methods



















RN2606(TE85L,F) Shipping Methods













If you have any question about RN2606(TE85L,F), please do not hesitate to contact us!

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